BGS12AL7-4 SPDT RF Switch

Small Signal Discretes



Never stop thinking

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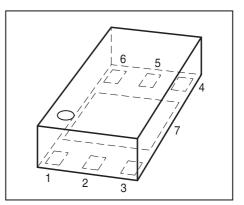


BGS12AL7-4

Features

- Low insertion loss
- High port-to-port-isolation
- Low harmonic generation
- On-chip control logic
- · High ESD robustness
- · No external components required
- · General purpose switch for applications up to 3 GHz
- Small leadless package TSLP-7-4
- · Lead and halogen free package (RoHS and WEEE compliant)





Description

The BGS12AL7-4 General Purpose RF MOS switch is designed to cover a broad range of applications from 0.1 to 3 GHz. The symmetric design of its single pole double throw configuration, as shown in **Figure 1** offers high design flexibility. This single supply chip integrates on-chip CMOS logic driven by a simple, single-pin CMOS or TTL compatible control input signal. The 0.1 dB compression point exceeds the switch's maximum input power level of 21 dBm, resulting in linear performance at all signal levels. The RF switch has a very low insertion loss of 0.35 dB in the 1 GHz and 0.65 dB in the 2 GHz range.

Unlike GaAs technology, external DC blocking capacitors at the RF ports are only required if DC voltage is applied externally.

The BGS12AL7-4 RF switch is manufactured in Infineon's patented MOS technology, offering the performance of GaAs with the economy and integration of conventional CMOS including the inherent higher ESD robustness.

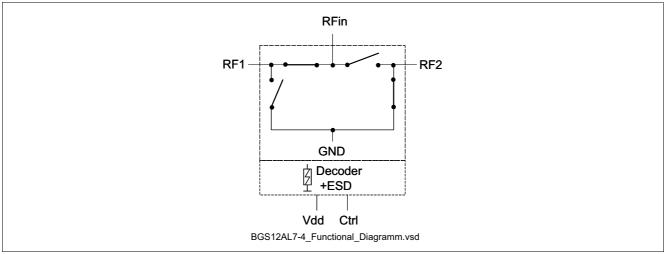


Figure 1 Functional Diagram

Туре	Package	Marking	Chip
BGS12AL7-4	TSLP-7-4	12	M4781



Table 1 Maximum Ratings

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.	1	Test Condition
Storage temperature range	$T_{\rm stg}$	-65		150	°C	
DC Voltage at all pins to GND	V _{DC}			5	V	
RF power max. at all RF ports	P _{IN}			24	dBm	
ESD Capability		1		1		
Human Body- JEDEC JESD22-A114 Machine-Model JEDEC JESD22-A115	V _{ESD}			1000 250	V	

Table 2Operation Ranges

Parameter	Symbol	Values			Unit	Note /
		Min.	Тур.	Max.	-	Test Condition
Ambient temperature	T _A	-30		85	°C	
RF Frequency	f	0.1		3	GHz	
Control voltage low	V _{CtrL}	-0.3		0.3	V	
Control voltage high	V _{CtrlH}	1.4		Vdd	V	
Supply voltage ¹⁾	V _{dd}	2.4		2.8	V	
Current consumption Vdd Pin (over temperature)	I _{Vdd}	80		350	μA	
Current Consumption Vctrl Pin	I _{Ctrl}			30	μA	
Power Range	P _{in}				dBm	
(VSWR ∞: 1))				15		
(VSWR 3: 1)				18		
(VSWR 1: 1)				21		

1) Supply voltage must be connected before Control Voltage



Table 3	Table 3 Pin description					
Pin	Name	Description				
1	RF2	RF Port 2 Out				
2	GND	Ground				
3	RF1	RF Port 1 Out				
4	Vdd	Supply Voltage				
5	RFIN	RF Port In				
6	CTRL	Control Pin				

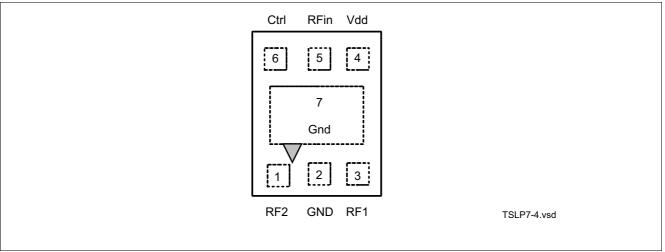


Figure 2 Pin Configuration (top view)

Table 4 Truth Table

Ctrl 1	RF 1	RF 2
0	1	0
1	0	1



Electrical Specifications

- Termination port impedance: $Z_0 = 50 \Omega$
- Temperature range: T = -30 °C...+85 °C
- Supply Voltage: V_{dd} = 2.8 V
- *P*_{in} = 15 dBm
- Across operating range of control voltages: $V_{\rm CtrH}$ = 1.4...2.8 V

Table 5 Electrical Characteristics

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
Insertion Loss	IL		0.4 ¹⁾		dB	f = 1 GHz TX,
			0.5 ¹⁾		dB	f = 2 GHz TX,
Return Loss	RL	15	22		dB	<i>f</i> = 1 GHz
		15	22		dB	<i>f</i> = 2 GHz
Isolation RFin - RF1	ISO _{RFin-RF1}	20	32		dB	<i>f</i> = 1 GHz
		15	25		dB	<i>f</i> = 2 GHz
Isolation RFin - RF2	ISO _{RFin-RF2}	20	32		dB	<i>f</i> = 1 GHz
		15	25		dB	<i>f</i> = 2 GHz
Isolation RF1 - RF2	ISO _{RF1-RF2}	24	32		dB	<i>f</i> = 1 GHz
		15	25		dB	<i>f</i> = 2 GHz
Isolation RF ports - Vdd, Vctrl	ISO _{RF-DC}	30	35		dB	<i>f</i> = 1 GHz
		20	35		dB	<i>f</i> = 2 GHz
Harmonic Generation up to 12.75 GHz	P _{Harm}		-75	-50	dBm	<i>f</i> = 1 GHz
			-80	-50	dBm	<i>f</i> = 2 GHz
On Switching Time (10-90%) RF	t _{on}			5	μs	<i>f</i> = 1 GHz
Off Switching Time (10-90%) RF	t _{off}			5	μs	<i>f</i> = 1 GHz
Current Consumption at Vdd Pin	$I_{\rm dd}$		120		μA	
Input 0.1 dB compression	$P_{0.1 \mathrm{dB}}$	21			dBm	<i>f</i> = 1 GHz
$\frac{1}{1} \otimes T_{r} = 25 ^{\circ} \text{C}$	0.108					J

1)@*T*_A = 25 °C



Measurement Results (@ T = 25°C)

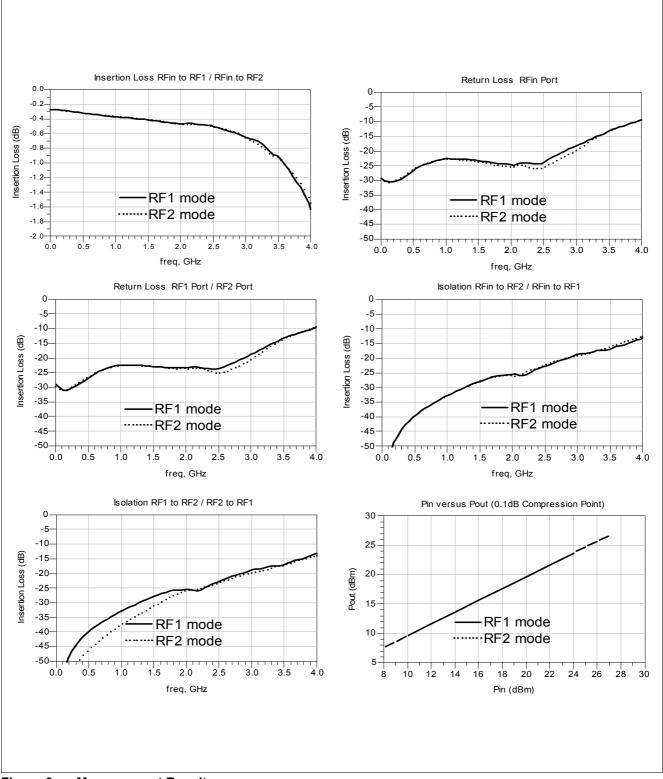
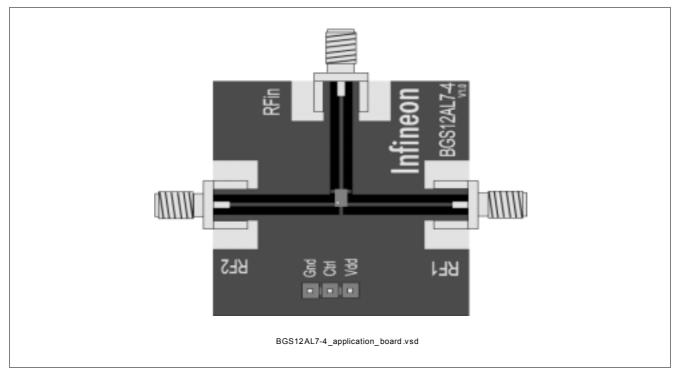
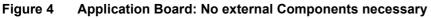


Figure 3 Measurement Results



Application Board





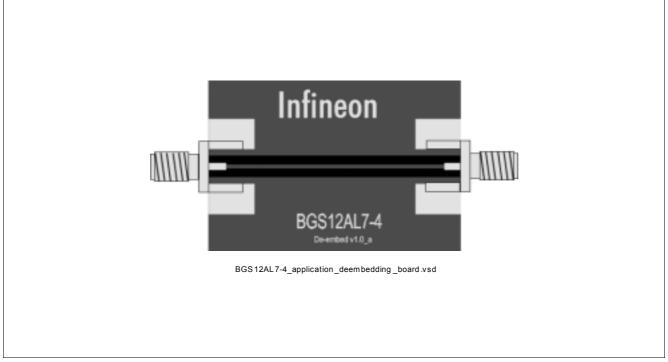
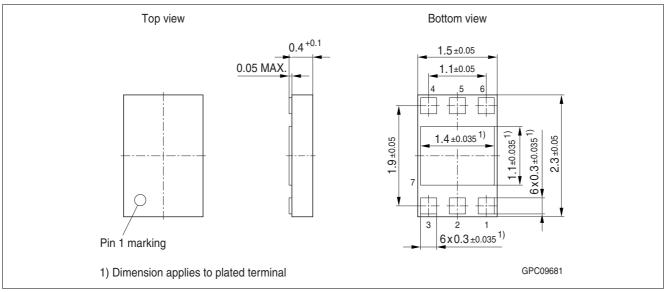


Figure 5 Application Deembedding Board



Package Outlines





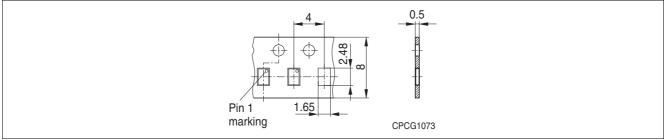


Figure 7 Tape Info

Dimensions in mm

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